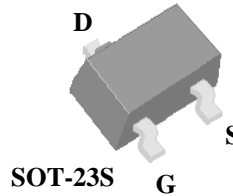
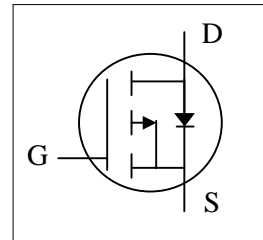




- ▼ Capable of 2.5V Gate Drive
- ▼ Small Package Outline
- ▼ Surface Mount Device
- ▼ RoHS Compliant & Halogen-Free



$BV_{DSS}$	-30V
$R_{DS(ON)}$	80m $\Omega$
$I_D$	-3.2A



### Description

AP3P080 series are from Advanced Power innovated design and silicon process technology to achieve the lowest possible on-resistance and fast switching performance. It provides the designer with an extreme efficient device for use in a wide range of power applications.

The SOT-23S package is widely preferred for commercial-industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

### Absolute Maximum Ratings @ $T_J=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	- 30	V
$V_{GS}$	Gate-Source Voltage	$\pm 12$	V
$I_D @ T_A=25^\circ\text{C}$	Drain Current <sup>3</sup> , $V_{GS}$ @ 4.5V	-3.2	A
$I_D @ T_A=70^\circ\text{C}$	Drain Current <sup>3</sup> , $V_{GS}$ @ 4.5V	-2.6	A
$I_{DM}$	Pulsed Drain Current <sup>1</sup>	-10	A
$P_D @ T_A=25^\circ\text{C}$	Total Power Dissipation <sup>3</sup>	1.25	W
$T_{STG}$	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$T_J$	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$

### Thermal Data

Symbol	Parameter	Value	Unit
Rthj-a	Maximum Thermal Resistance, Junction-ambient <sup>3</sup>	100	$^\circ\text{C}/\text{W}$



# AP3P080N

## Electrical Characteristics @T<sub>j</sub>=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-3A	-	-	60	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3A	-	-	80	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2A	-	-	150	mΩ
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.3	-	-1.2	V
g <sub>fs</sub>	Forward Transconductance	V <sub>DS</sub> =-5V, I <sub>D</sub> =-3A	-	11	-	S
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =-24V, V <sub>GS</sub> =0V	-	-	-10	uA
I <sub>GSS</sub>	Gate-Source Leakage	V <sub>GS</sub> = ±12V, V <sub>DS</sub> =0V	-	-	±100	nA
Q <sub>g</sub>	Total Gate Charge	I <sub>D</sub> =-3A	-	8.5	13.6	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>DS</sub> =-15V	-	1.2	-	nC
Q <sub>gd</sub>	Gate-Drain ("Miller") Charge	V <sub>GS</sub> =-4.5V	-	2	-	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =-15V	-	6	-	ns
t <sub>r</sub>	Rise Time	I <sub>D</sub> =-1A	-	10	-	ns
t <sub>d(off)</sub>	Turn-off Delay Time	R <sub>G</sub> =3.3Ω	-	40	-	ns
t <sub>f</sub>	Fall Time	V <sub>GS</sub> =-10V	-	22	-	ns
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V	-	810	1296	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> =-15V	-	85	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f=1.0MHz	-	60	-	pF

## Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V <sub>SD</sub>	Forward On Voltage <sup>2</sup>	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-	-1.2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>S</sub> =-3A, V <sub>GS</sub> =0V,	-	11	-	ns
Q <sub>rr</sub>	Reverse Recovery Charge	dI/dt=100A/μs	-	4	-	nC

### Notes:

- 1.Pulse width limited by Max. junction temperature.
- 2.Pulse test
- 3.Surface mounted on 1 in<sup>2</sup> copper pad of FR4 board, t ≤ 10s ; 300°C/W when mounted on min. copper pad.

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

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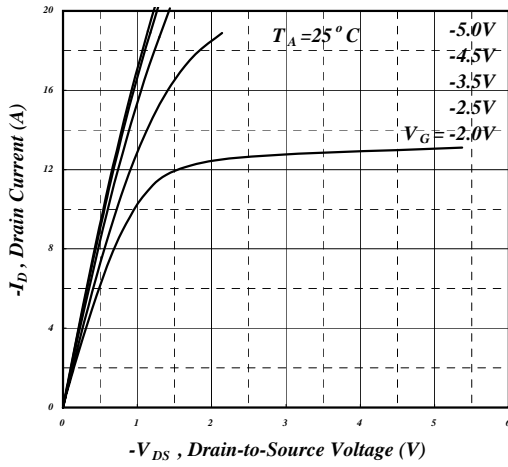


Fig 1. Typical Output Characteristics

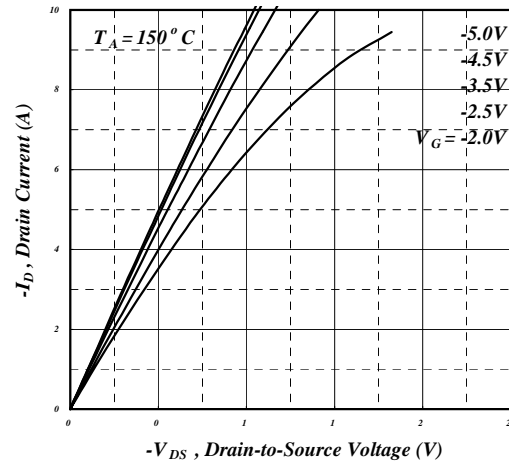


Fig 2. Typical Output Characteristics

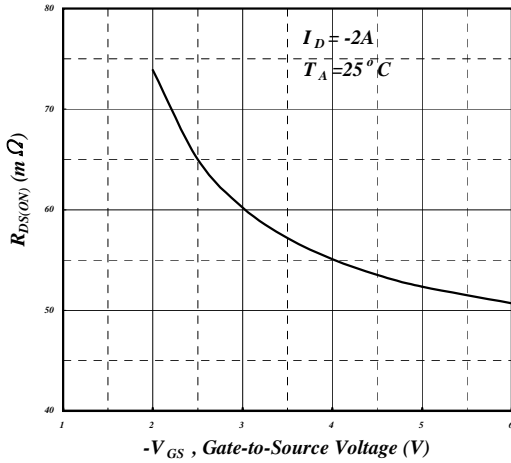


Fig 3. On-Resistance v.s. Gate Voltage

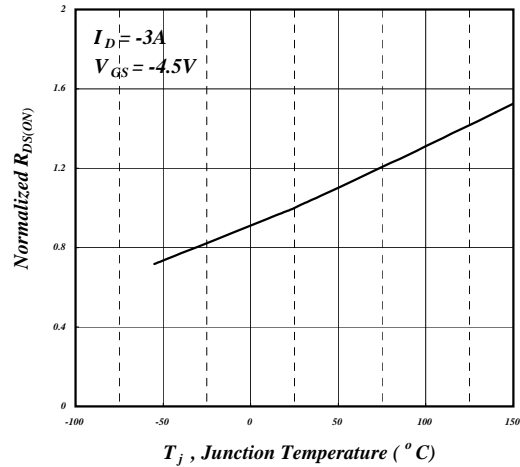


Fig 4. Normalized On-Resistance v.s. Junction Temperature

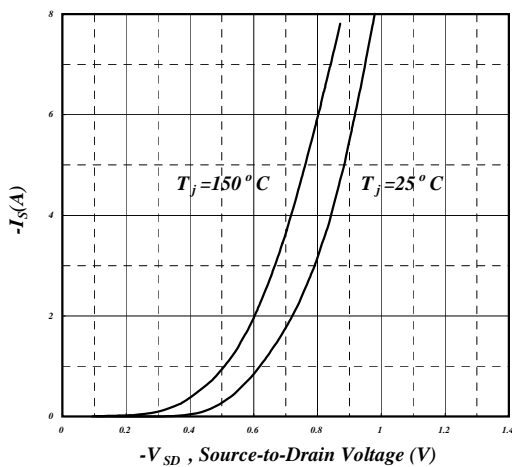


Fig 5. Forward Characteristic of Reverse Diode

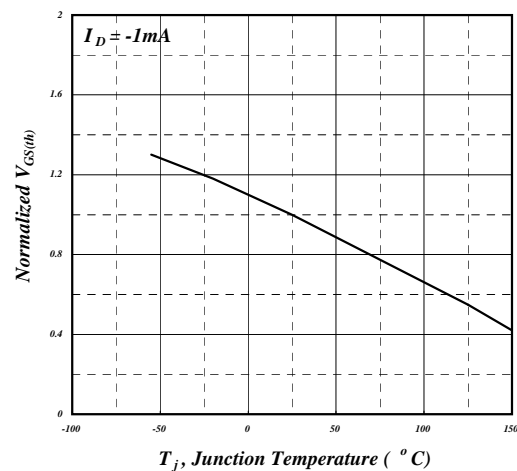
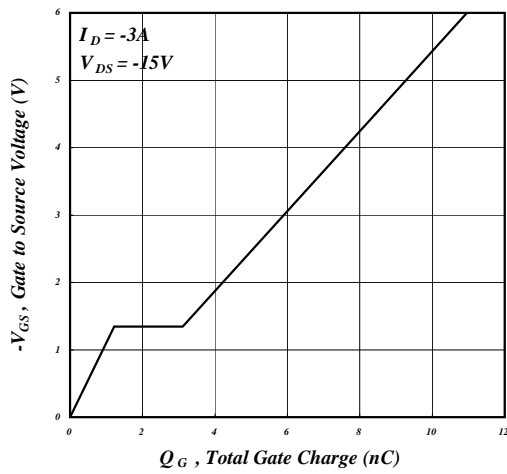
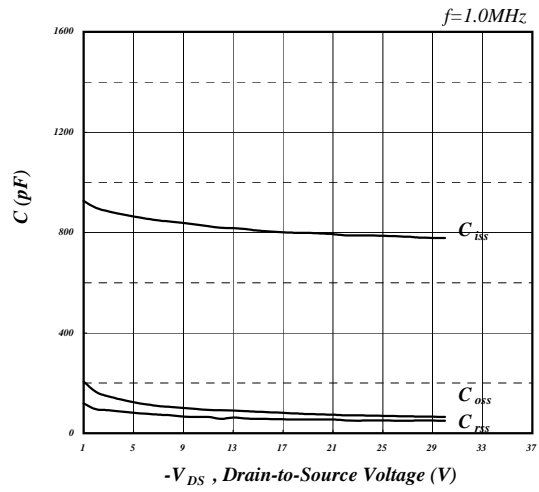


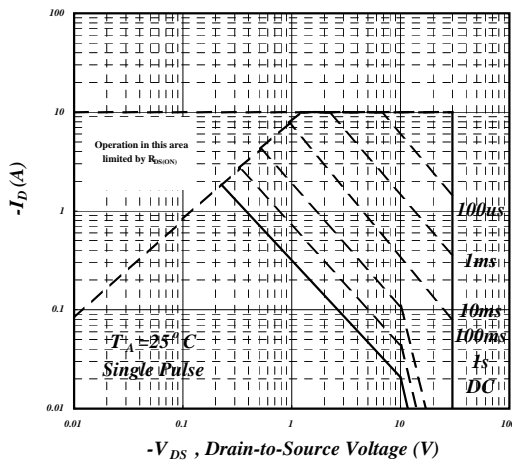
Fig 6. Gate Threshold Voltage v.s. Junction Temperature



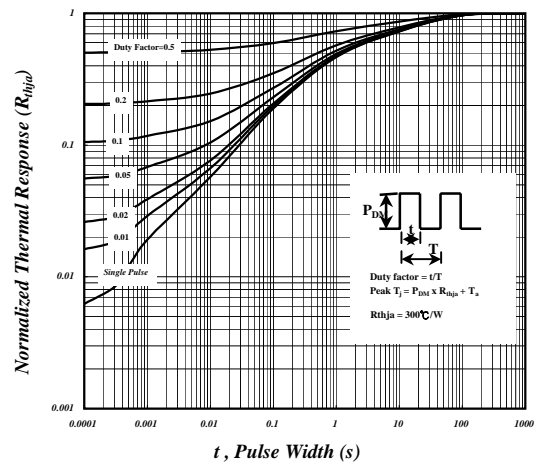
**Fig 7. Gate Charge Characteristics**



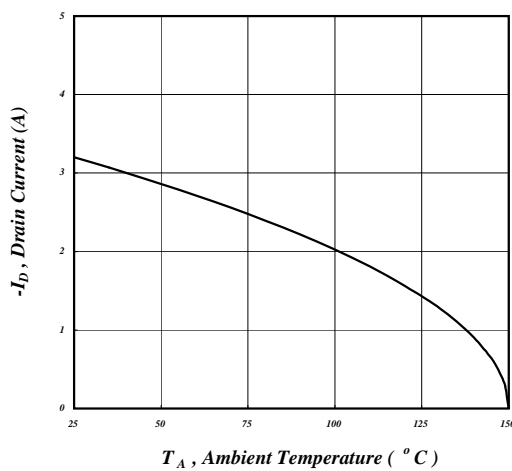
**Fig 8. Typical Capacitance Characteristics**



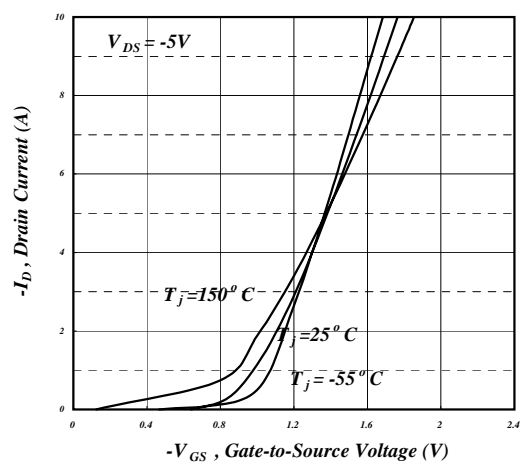
**Fig 9. Maximum Safe Operating Area**



**Fig 10. Effective Transient Thermal Impedance**



**Fig 11. Drain Current v.s. Ambient Temperature**



**Fig 12. Transfer Characteristics**

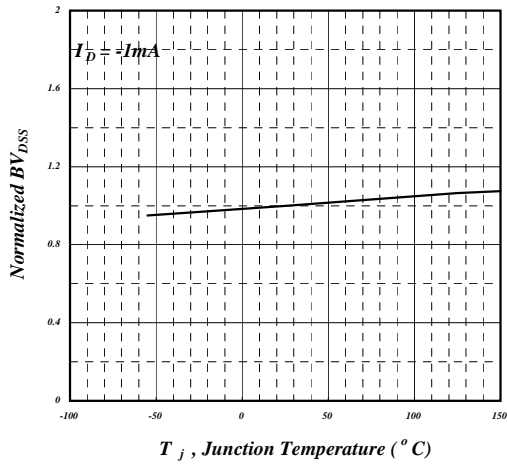


Fig 13. Normalized  $BV_{DSS}$  v.s. Junction Temperature

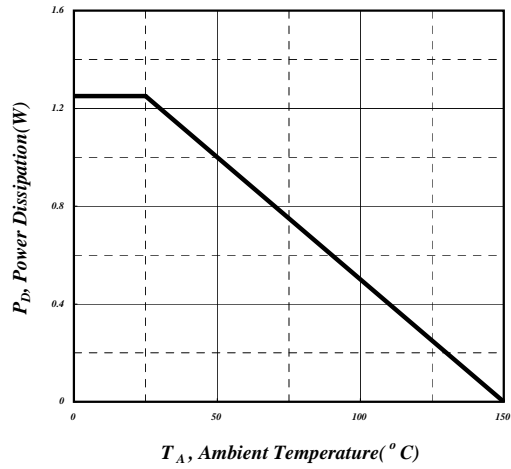


Fig 14. Total Power Dissipation

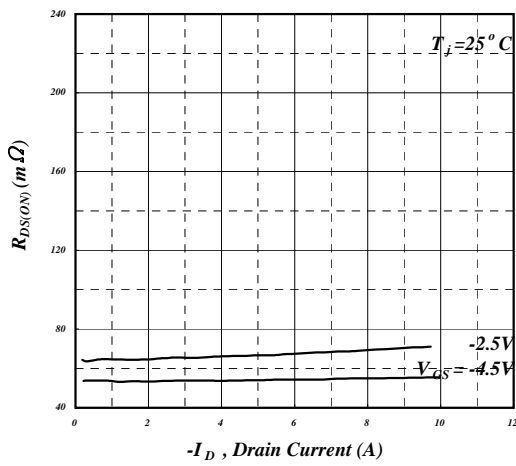


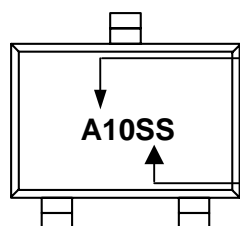
Fig 15. Typ. Drain-Source on State Resistance



# AP3P080N

## MARKING INFORMATION

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Part Number : A10

Date Code : SS

SS:2004,2008,2012,2016,2020...

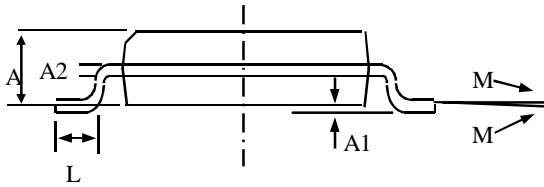
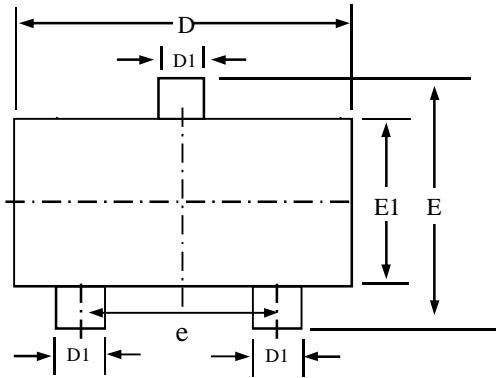
SS:2003,2007,2011,2015,2019...

SS:2002,2006,2010,2014,2018...

SS:2001,2005,2009,2013,2017...



## Package Outline : SOT-23S



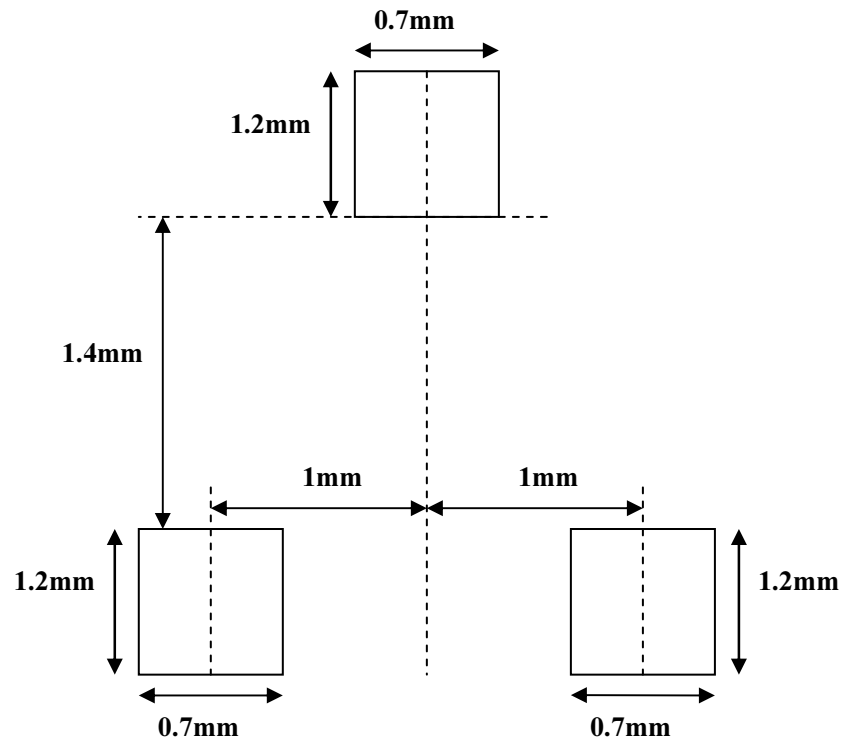
SYMBOLS	Millimeters		
	MIN	NOM	MAX
A	0.80	1.00	1.20
A1	0.00	—	0.10
A2	0.05	—	0.20
D1	0.30	0.40	0.50
e	1.80	1.90	2.00
D	2.80	2.90	3.10
E	2.10	2.40	2.70
E1	1.20	1.30	1.40
M	0°	5°	10°
L	0.20	—	0.60

1.All Dimension Are In Millimeters.

2.Dimension Does Not Include Mold Protrusions.



SOT-23S FOOTPRINT :





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